**Preferred Device** 

## **SWITCHMODE™ Ultrafast Power Rectifier**

... designed for use in negative switching power supplies, inverters and as free wheeling diode. Also, used in conjunction with a standard cathode dual Ultrafast Rectifier, makes a single phase full—wave bridge. These state—of—the—art devices have the following features:

- Reverse Polarity Rectifier
- Ultrafast 95 Nanosecond Reverse Recovery Times
- Exhibits Soft Recovery Characteristics
- High Temperature Glass Passivated Junction
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Case Temperature
- Epoxy Meets UL94, V<sub>O</sub> @ 1/8"

#### **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: U2020R

#### MAXIMUM RATINGS (Per Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	Volts
Average Rectified Forward Voltage, (Rated V <sub>R</sub> ), T <sub>C</sub> = 125°C	I <sub>F(AV)</sub>	20	Amps
Peak Repetitive Forward Current (Rated V <sub>R</sub> ), T <sub>C</sub> = 125°C	I <sub>FRM</sub>	40	Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	250	Amps
Operating Junction Temperature and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175	°C



#### ON Semiconductor™

http://onsemi.com

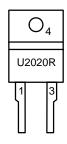
# ULTRAFAST RECTIFIER 20 AMPERES 200 VOLTS





TO-220AC CASE 221B PLASTIC

#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

Device	Package	Shipping	
MUR2020R	TO-220AC	50 Units/Rail	

**Preferred** devices are recommended choices for future use and best overall value.

#### THERMAL CHARACTERISTICS (Per Leg)

Characteristic	Symbol	Value	Unit
Thermal Resistance – Junction to Case	$R_{ heta JC}$	2.0	°C/W
ELECTRICAL CHARACTERISTICS (Per Leg)	<u> </u>		
Maximum Instantaneous Forward Voltage (Note 1.) $ (I_F = 20 \text{ Amps}, T_C = 25^{\circ}\text{C}) $ $ (I_F = 20 \text{ Amps}, T_C = 150^{\circ}\text{C}) $	V <sub>F</sub>	1.1 1.0	Volts
Maximum Instantaneous Reverse Current (Note 1.) (Rated dc Voltage, $T_C = 25^{\circ}C$ ) (Rated dc Voltage, $T_C = 150^{\circ}C$ )	I <sub>R</sub>	50 1	μA mA
Maximum Reverse Recovery Time (I <sub>F</sub> = 1.0 Amp, di/dt = 50 Amps/μs) (I <sub>F</sub> = 1.0 Amp, di/dt = 100 Amps/μs)	t <sub>rr</sub>	95 75	ns

<sup>1.</sup> Pulse Test: Pulse Width = 5.0 ms, Duty Cycle  $\leq 10\%$ .

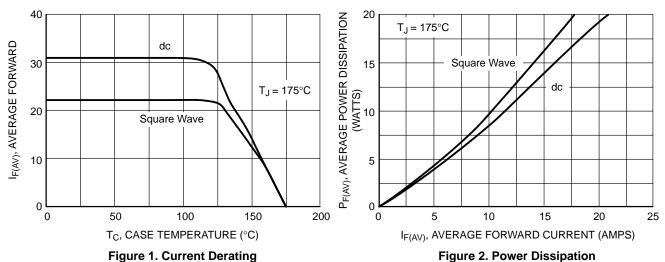


Figure 1. Current Derating

√<sub>F</sub> @ 25°C

1.3

1.5

V<sub>F</sub> @ 175°C

IF, INSTANTANEOUS FORWARD CURRENT

(AMPS)

10

اً 1. 0.3

V<sub>F</sub> @ 100°C

0.5

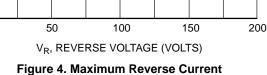
1000.00 I<sub>r</sub> @ 175°C I<sub>R</sub>, REVERSE CURRENT (μA) 00°000 00°00 0 I<sub>r</sub> @ 100°C ์ I<sub>r</sub> @ 25°C 10.00

V<sub>F</sub>, INSTANTANEOUS VOLTAGE (VOLTS) Figure 3. Maximum Forward Voltage

0.9

0.7

1.1



1.00

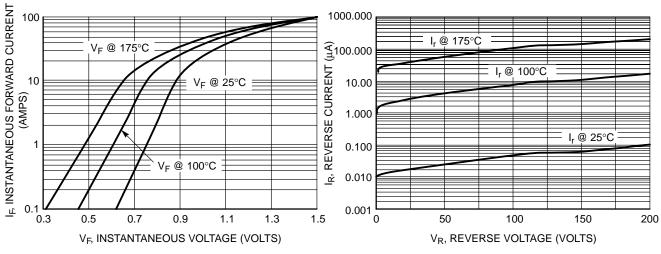


Figure 5. Typical Forward Voltage

**Figure 6. Typical Reverse Current** 

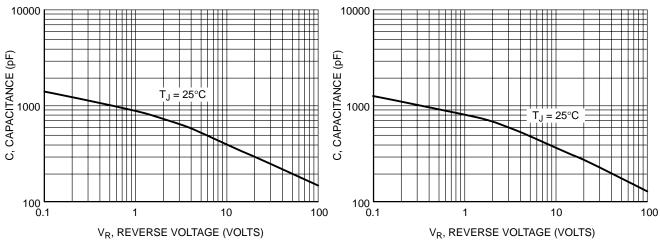


Figure 8. Maximum Capacitance

Figure 9. Typical Capacitance

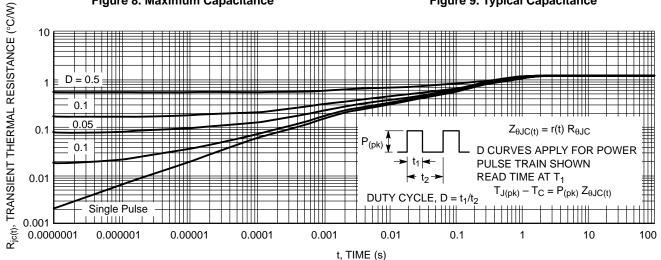
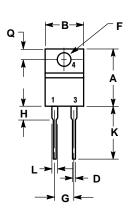


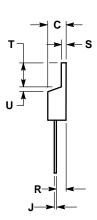
Figure 7. Thermal Response

#### PACKAGE DIMENSIONS

#### TO-220 TWO-LEAD

CASE 221B-04 ISSUE D





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
7	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

STYLE 2:

PIN 1. ANODE

N/A
 CATHODE

4. ANODE

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